PANJIT SEMI CONDUCTOR

CBD10120LCT

LOW VF SCHOTTKY RECTIFIER

VOLTAGE 120 Volts **CURRENT** 10 Amperes

FEATURES

- Low forward voltage drop, low power losses
- High efficiency operation
- In compliance with EU RoHS 2002/95/EC directives

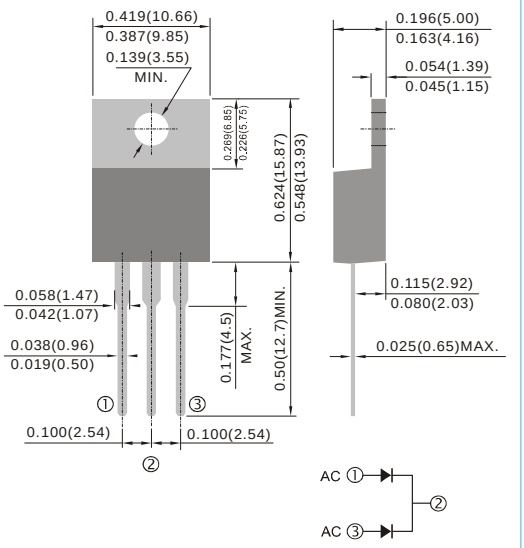
MECHANICAL DATA

Case : TO-220AB, Plastic

Terminals : Solderable per MIL-STD-750, Method 2026

Weight: 0.0655 ounces, 1.859 grams.

TO-220AB Unit : inch(mm)



PRELIMINARY

MAXIMUM RATINGS(T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	VALUE	UNIT
Maximum repetitive peak reverse voltage		V_{RRM}	120	V
Maximum average forward rectified current	per device per diode	$I_{F(AV)}$	10 5	A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	per diode	I_{FSM}	125	A
Typical thermal resistance per diode	(Note 1)	$R_{\Theta JC}$	2.2	°C/W
Operating junction temperature range		T_J	-55 to + 150	°C
Storage temperature range		T_{STG}	-55 to + 150	°C

ELECTRICAL CHARACTERISTICS(T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Breakdown voltage per diode	V_{BR}	I_R=1mA		120	-	-	V
Instantaneous forward voltage per diode	V_F	I_F=1A I_F=2A I_F=5A	T_J=25°C	- - -	0.48 0.57 0.71	- - 0.75	V
		I_F=1A I_F=2A I_F=5A	T_J=125°C	- - -	0.39 0.47 0.57	- - -	V
Reverse current per diode	I_R	V_R=96V		-	2	-	μA
		V_R=120V	T_J=25°C T_J=125°C	- -	- 3.68	30 -	μA mA

Note : 1. Mounted on infinite heatsink.

PRELIMINARY

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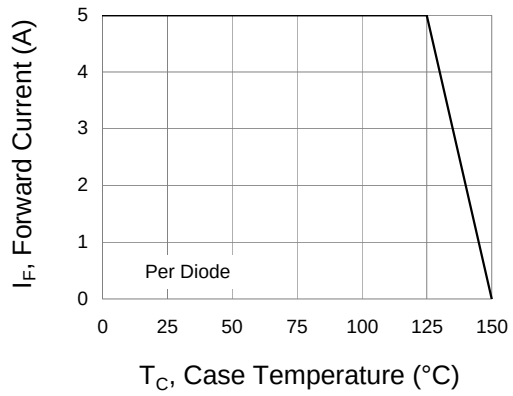

Fig.1 Forward Current Derating Curve

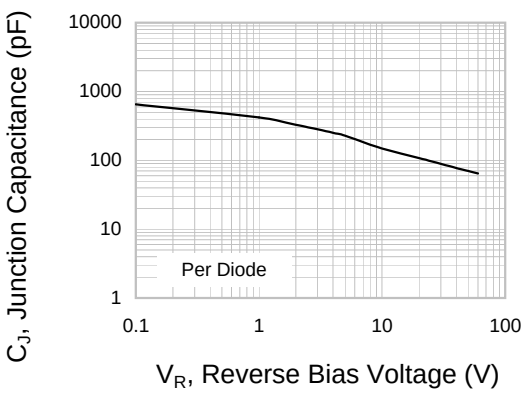

Fig.2 Typical Junction Capacitance

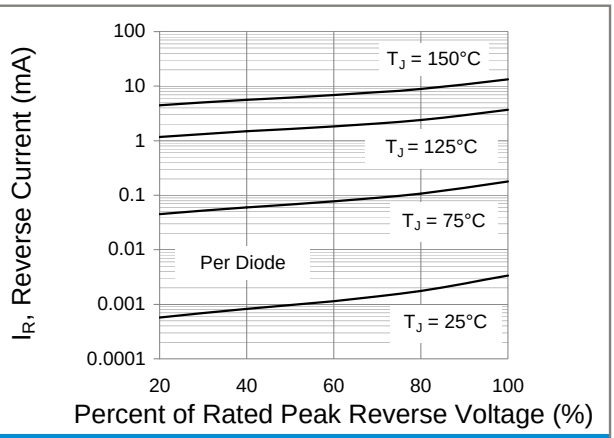

Fig.3 Typical Reverse Characteristics

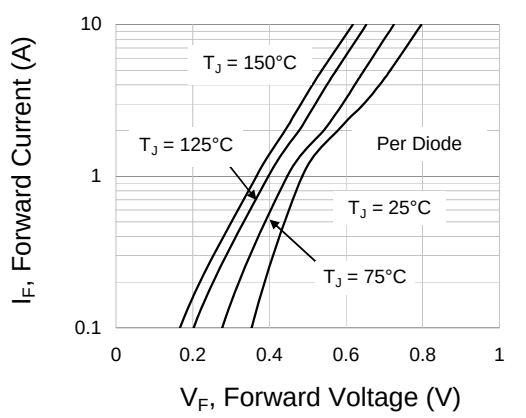

Fig.4 Typical Forward Characteristics